

YJ Planar Schottky Barrier Diode Die Specification

45V 30A, 158mil, Schottky barrier diode die based on silicon planar process

Part No.: PSB158M045AS-290A

Main Products Characteristics

- Average forward current: $I_{F(AV)} = 30 \text{ A}$
- Maximum operating junction temperature: $T_{jmax} = 175^\circ \text{C}$